In Reply to USPTO Correspondence of N/A

Attorney Docket No. 1217-032261

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims

- 1. (Currently Amended) A single crystal pulling apparatus for a metal fluoride, comprising:
 - a chamber constituting a crystal growth furnace;
- a crucible provided in the chamber and for filling with a molten solution of a single crystal manufacturing material;
 - a melting heater provided to surround the crucible;
- a vertically movable single crystal pulling bar including-for attaching a seed crystal on a tip and coming adapted to come in contact with the molten solution of the single crystal manufacturing-material filled in the crucible;
- a heat insulating wall provided in the chamber to surround at least a peripheral side portion of a single crystal pulling region in an upper part of the crucible;
- a ceiling board for closing an opening portion of an upper end in an upper part of the heat insulating wall; and
- a single crystal pulling chamber surrounded by the heat insulating wall and the ceiling board,
- wherein the ceiling board is provided with at least an inserting hole for inserting the single crystal pulling bar, and
- a coefficient of thermal conductivity in a direction of a thickness of the ceiling board is 1000 to 50000 W/m^2 · K.
- 2. (Original) The single crystal pulling apparatus for a metal fluoride according to claim 1, wherein a coefficient of thermal conductivity in a direction of a thickness of the heat insulating wall is 100 W/m^2 . K or less.
- 3. (Currently Amended) The single crystal pulling apparatus for a metal fluoride according to claim 1-or 2, wherein the ceiling board is a graphite plate.

Page 5

{W0091976.1}

Application No. Not Yet Assigned Paper Dated: November 19, 2003 In Reply to USPTO Correspondence of N/A

Attorney Docket No. 1217-032261

- 4. (Currently Amended) The single crystal pulling apparatus for a metal fluoride according to any of claims 1 to 3 claim 1, wherein the ceiling board is positioned in a higher place than an upper end of the crucible by 50 to 500% of a maximum inside diameter of the crucible.
- 5. (Currently Amended) The single crystal pulling apparatus for a metal fluoride according to any of claims 1 to 4claim 1, wherein a total opening area of apertures formed on the ceiling board is 5 to 60% of an opening area of an upper end in a circular enclosure of the heat insulating wall.
- 6. (Currently Amended) The single crystal pulling apparatus for a metal fluoride according to any of claims 1 to 5 claim 1, wherein the metal fluoride is calcium fluoride.
- 7. (Currently Amended) The single crystal pulling apparatus for a metal fluoride according to any of claims 1 to 6 claim 1, wherein the crucible has a maximum inside diameter of 11 cm or more.